### MMBV809LT1

**Preferred Device** 

# **Silicon Tuning Diode**

This device is designed for 900 MHz frequency control and tuning applications. It provides solid-state reliability in replacement of mechanical tuning methods.

#### **Features**

- Controlled and Uniform Tuning Ratio
- Available in Surface Mount Package
- Available in 8 mm Tape and Reel
- Pb-Free Packages are Available

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Reverse Voltage	V <sub>R</sub>	20	Vdc
Forward Current	ΙF	20	mAdc
Total Power Dissipation (Note 1)  @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Junction Temperature	TJ	+125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +125	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. FR5 Board 1.0 x 0.75 x 0.62 in.



#### ON Semiconductor®

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# 4.5–6.1 pF VOLTAGE VARIABLE CAPACITANCE DIODE





SOT-23 (TO-236) CASE 318 STYLE 8

#### **MARKING DIAGRAM**



5K = Specific Device Code

M = Date Code\*

= Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
MMBV809LT1	SOT-23	3,000 / Tape & Reel
MMBV809LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
MMBV809LT3	SOT-23	10,000 / Tape & Reel
MMBV809LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

**Preferred** devices are recommended choices for future use and best overall value.

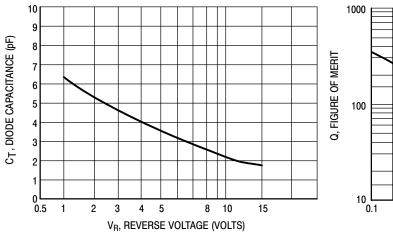
#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic - All Types	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage $(I_R = 10 \mu Adc)$	$V_{(BR)R}$	20	-	-	Vdc
Reverse Voltage Leakage Current (V <sub>R</sub> = 15 Vdc)	I <sub>R</sub>	-	-	50	nAdc

	C <sub>t</sub> , Diode Capacitance V <sub>R</sub> = 2.0 Vdc, f = 1.0 MHz pF		Q, Figure of Merit V <sub>R</sub> = 3.0 Vdc f = 500 MHz	C <sub>R</sub> , Capacitance Ratio C <sub>2</sub> /C <sub>8</sub> f = 1.0 MHz (Note 2)		
Device	Min	Тур	Max	Тур	Min	Max
MMBV809LT1	4.5	5.3	6.1	75	1.8	2.6

<sup>2.</sup>  $C_R$  is the ratio of  $C_t$  measured at 2.0 Vdc divided by  $C_t$  measured at 8.0 Vdc.

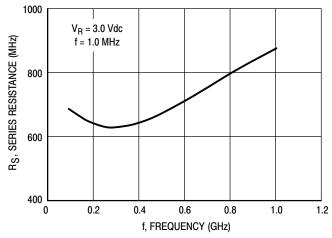
#### **TYPICAL CHARACTERISTICS**



100 V<sub>R</sub> = 3 Vdc T<sub>A</sub> = 25°C T

Figure 1. Diode Capacitance

Figure 2. Figure of Merit



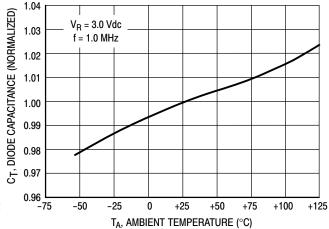


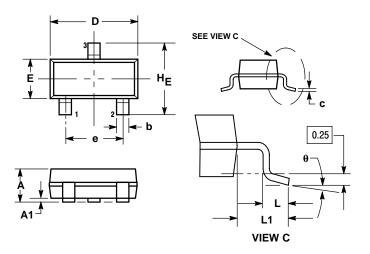
Figure 3. Series Resistance

Figure 4. Diode Capacitance

#### MMBV809LT1

#### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 ISSUE AN



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
   VAA EM 4002
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

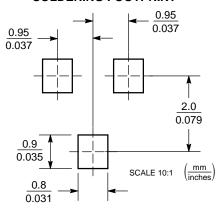
	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.89	1.00	1.11	0.035	0.040	0.044	
A1	0.01	0.06	0.10	0.001	0.002	0.004	
b	0.37	0.44	0.50	0.015	0.018	0.020	
С	0.09	0.13	0.18	0.003	0.005	0.007	
D	2.80	2.90	3.04	0.110	0.114	0.120	
E	1.20	1.30	1.40	0.047	0.051	0.055	
е	1.78	1.90	2.04	0.070	0.075	0.081	
L	0.10	0.20	0.30	0.004	0.008	0.012	
L1	0.35	0.54	0.69	0.014	0.021	0.029	
HE	2.10	2.40	2.64	0.083	0.094	0.104	

#### STYLE 8:

PIN 1. ANODE

- 2. NO CONNECTION
- 3. CATHODE

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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